

### Description

The KIT5033C is a photo interrupter high-performance standard type, combines high-output GaAs IRED with high sensitive phototransistor..

### Features

- Snap-in mount
- GAP : 5.0mm
- 3 kinds of mounting plate thicknesses :  
1.0mm, 1.2mm, 1.6mm
- RoHS compliant



### Applications

- Printers.
- Copiers
- ATM
- Ticket vending machines

### Absolute Maximum Ratings (T<sub>a</sub>=25°C, Unless otherwise specified)

Characteristic		Symbol	Ratings	Unit
Input	Power Dissipation	P <sub>D</sub>	75	mW
	Forward Current	I <sub>F</sub>	50	mA
	Reverse Voltage	V <sub>R</sub>	6	V
	Peak Forward Current <sup>*1</sup>	I <sub>FP</sub>	1	A
Output	Collector Current	I <sub>C</sub>	20	mA
	Collector-Emitter Voltage	V <sub>CEO</sub>	35	V
	Emitter-Collector Voltage	V <sub>ECO</sub>	6	V
Operating Temperature <sup>*2</sup>		T <sub>opr</sub>	-30 ~ +95	°C
Storage Temperature <sup>*2</sup>		T <sub>stg</sub>	-40 ~ +100	°C

\*1 : Pulse width (tw) ≤ 100μs, Period (T) = 10msec.

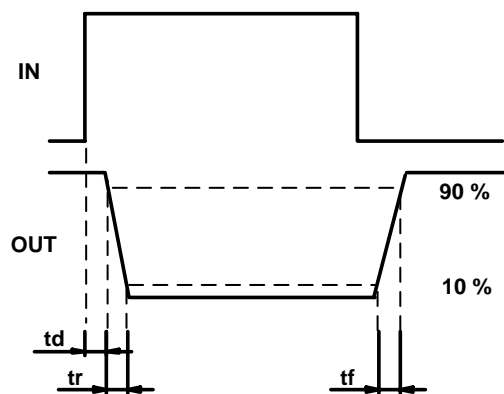
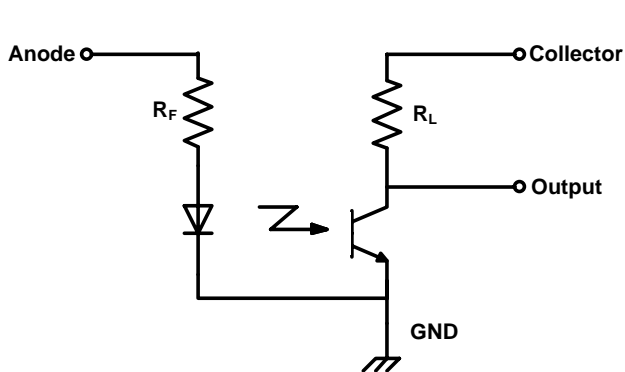
\*2 : No icebond or dew.

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## Electrical Characteristics (T<sub>a</sub>=25°C)

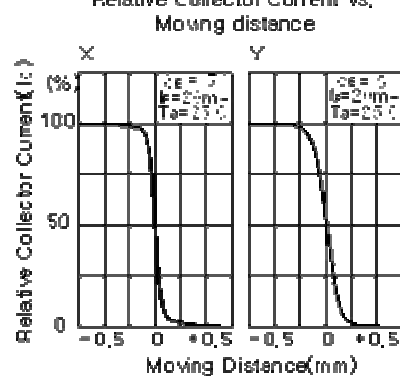
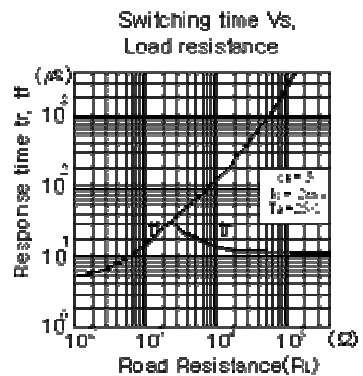
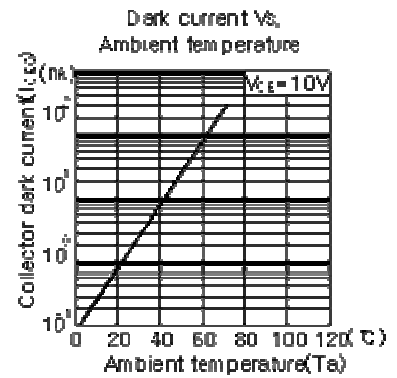
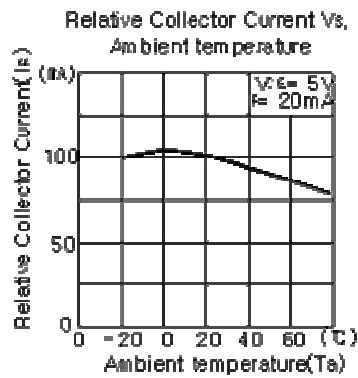
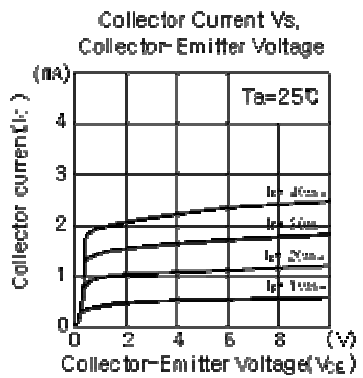
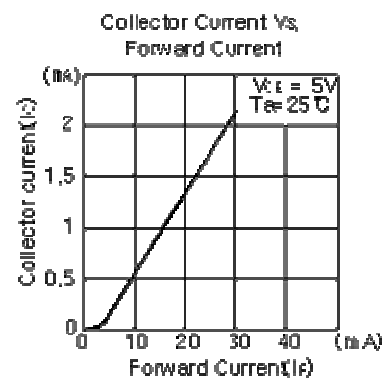
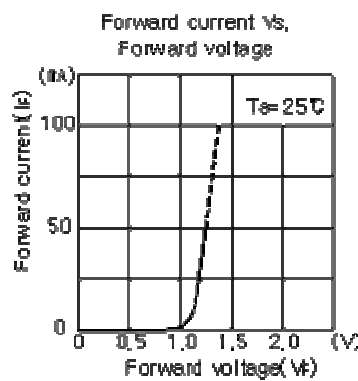
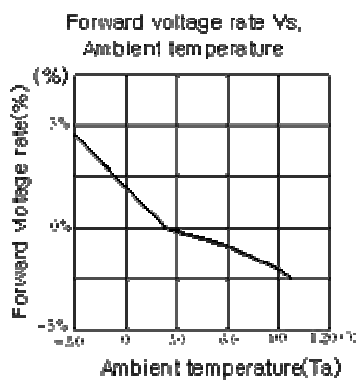
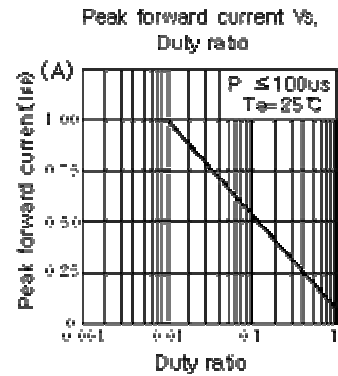
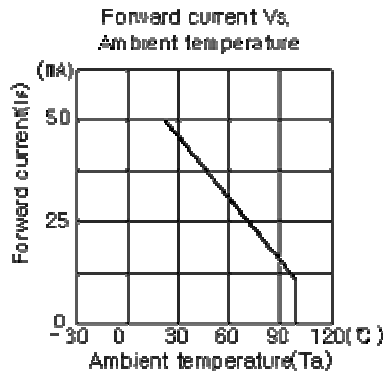
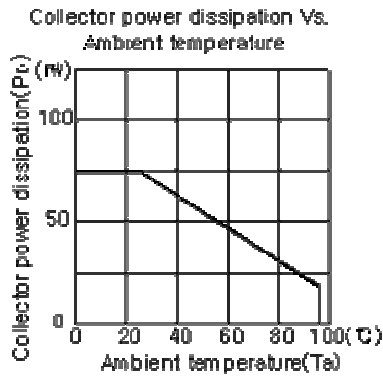
Characteristic		Symbol	Test Condition	Min.	Typ.	Max.	Unit
Input	Forward Voltage	V <sub>F</sub>	I <sub>F</sub> =20mA	-	1.2	1.4	V
	Peak Wavelength	λ <sub>p</sub>	I <sub>F</sub> =20mA	-	940	-	nm
	Reverse Current	I <sub>R</sub>	V <sub>R</sub> =5V	-	-	10	uA
Output	Dark Current	I <sub>CEO</sub>	V <sub>CE</sub> =10V, E=0lux	-	1	100	nA
	Peak Wavelength	λ <sub>p</sub>	-	-	880	-	nm
Transfer Characteristics	Collector Current	I <sub>C</sub>	V <sub>CE</sub> =5.0V, I <sub>F</sub> =20mA	0.5	-	15.0	mA
	C-E Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =0.5mA, I <sub>F</sub> =20mA	-	-	0.4	V
Response Time	Rise Time	t <sub>r</sub>	V <sub>CC</sub> =5.0V, I <sub>C</sub> =2mA RL=100Ω	-	3	15	usec
	Fall Time	t <sub>f</sub>		-	4	20	usec

\* Circuit for Measuring Response Time

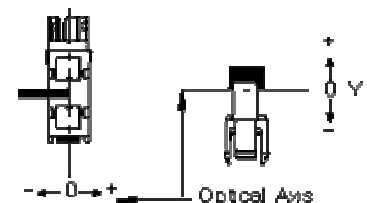


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## Characteristics



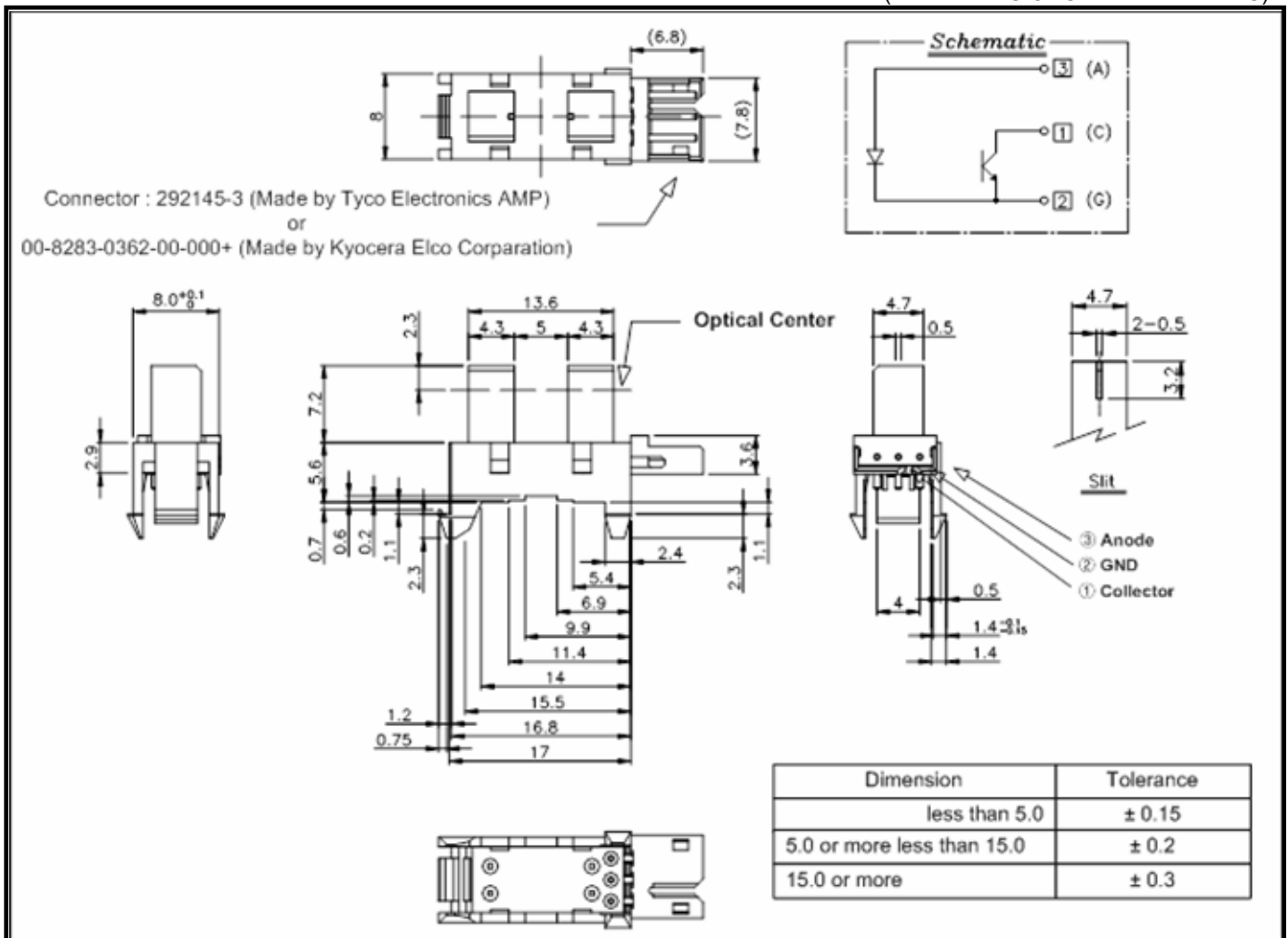
Method of measuring position detection characteristic



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## Package Outline Dimensions

(ALL DIMENSIONS IN MILLIMETERS)



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